

1.5-Gbps 2 × 2 LVDS CROSSPOINT SWITCH

FEATURES

- Designed for Signaling Rates ⁽¹⁾ Up To 1.5 Gbps
- Total Jitter < 65 ps
- Pin-Compatible With SN65LVDS22 and SN65LVDM22
- 25 mV of Receiver Input Threshold Hysteresis Over 0-V to 4-V Common-Mode Range
- Inputs Electrically Compatible With CML, LVPECL and LVDS Signal Levels
- Propagation Delay Times, 900 ps Maximum
- LVDT Integrates 110-Ω Terminating Resistor
- Offered in SOIC and TSSOP

APPLICATIONS

- 10-G (OC-192) Optical Modules
- 622-MHz Central Office Clock Distribution
- Wireless Basestations
- Low Jitter Clock Repeater/Multiplexer
- Protection Switching for Serial Backplanes

- (1) The signaling rate of a line is the number of voltage transitions that are made per second expressed in the units bps (bits per second).

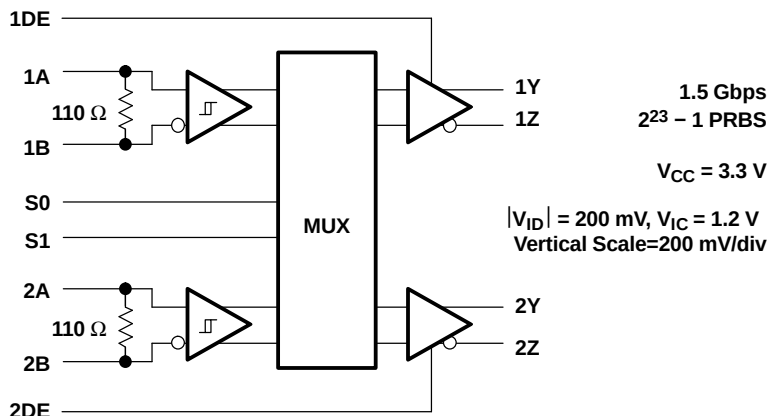
DESCRIPTION

The SN65LVDS122 and SN65LVDT122 are crosspoint switches that use low voltage differential signaling (LVDS) to achieve signaling rates as high as 1.5 Gbps. They are pin-compatible speed upgrades to the SN65LVDS22 and SN65LVDM22. The internal signal paths maintain differential signaling for high speeds and low signal skews. These devices have a 0-V to 4-V common-mode input range that accepts LVDS, LVPECL, or CML inputs. Two logic pins (S0 and S1) set the internal configuration between the differential inputs and outputs. This allows the flexibility to perform the following configurations: 2 × 2 crosspoint switch, 2:1 input multiplexer, 1:2 splitter or dual repeater/translator within a single device. Additionally, SN65LVDT122 incorporates a 110-Ω termination resistor for those applications where board space is a premium. Although these devices are designed for 1.5 Gbps, some applications at a 2-Gbps data rate can be supported depending on loading and signal quality.

The intended application of this device is ideal for loopback switching for diagnostic routines, fanout buffering of clock/data distribution provide protection in fault-tolerant systems, clock multiplexing in optical modules, and for overall signal boosting over extended distances.

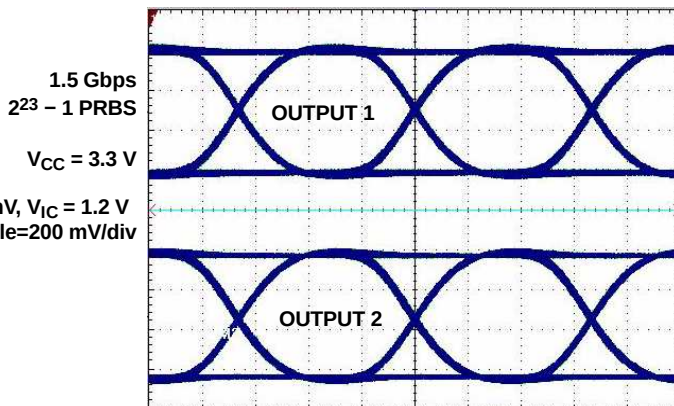
The SN65LVDS122 and SN65LVDT122 are characterized for operation from –40°C to 85°C.

FUNCTIONAL DIAGRAM



Integrated Termination on SN65LVDT122 Only

EYE PATTERNS OF OUTPUTS OPERATING SIMULTANEOUSLY



Horizontal Scale= 200 ps/div



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ORDERING INFORMATION

PACKAGE	TERMINATION RESISTOR	PART NUMBER ⁽¹⁾	SYMBOLIZATION
SOIC	No	SN65LVDS122D	LVDS122
SOIC	Yes	SN65LVDT122D	LVDT122
TSSOP	No	SN65LVDS122PW	LVDS122
TSSOP	Yes	SN65LVDT122PW	LVDT122

(1) Add the suffix R for taped and reeled carrier

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted⁽¹⁾

			SN65LVDS122, SN65LVDT122
V _{CC}	Supply voltage range ⁽²⁾		–0.5 V to 4 V
Voltage range	(A, B)		–0.7 V to 4.3 V
	V _A -V _B (LVDT only)		1 V
	(DE, S0, S1)		–0.5 V to 4 V
	(Y, Z)		–0.5 V to 4 V
ESD	Human Body Model ⁽³⁾	A, B, Y, Z, and GND	±4 kV
		All pins	±2 kV
	Charged-Device Model ⁽⁴⁾	All pins	±1500 V
Continuous power dissipation			See Dissipation Rating Table
T _{stg}	Storage temperature range		–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds			260°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.
- (3) Tested in accordance with JEDEC Standard 22, Test Method A114-A.7.
- (4) Tested in accordance with JEDEC Standard 22, Test Method C101.

RECOMMENDED OPERATING CONDITIONS

			MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage		3	3.3	3.6	V
V _{IH}	High-level input voltage	S0, S1, 1DE, 2DE	2		4	V
V _{IL}	Low-level input voltage	S0, S1, 1DE, 2DE	0		0.8	V
V _{ID}	Magnitude of differential input voltage	LVDS	0.1		1	V
		LVDT	0.1		0.8	
Input voltage (any combination of common-mode or input signals)			0		4	V
T _A	Operating free-air temperature		−40		85	°C

PACKAGE DISSIPATION RATINGS

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ⁽¹⁾ ABOVE $T_A = 25^\circ\text{C}$	$T_A = 85^\circ\text{C}$ POWER RATING
PW	712 mW	6.2 mW/°C	340 mW
D	1002 mW	8.7 mW/°C	480 mW

(1) This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

INPUT ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IT+}	Positive-going differential input voltage threshold	See Figure 1 and Table 1			100	mV
V _{IT-}	Negative-going differential input voltage threshold	See Figure 1 and Table 1	–100 ⁽²⁾			mV
V _{ID(HYS)}	Differential input voltage hysteresis (V _{IT+} – V _{IT-})			25		mV
I _{IH}	High-level input current	DE	–10		0	μA
		S0, S1	0		20	
I _{IL}	Low-level input current	DE	–10		0	μA
		S0, S1			20	
I _{CC}	Supply current	R _L = 100 Ω		80	100	mA
		Disabled		35	45	
I _I	Input current (A or B inputs 'LVDS)	V _I = 0 V or 2.4 V, Other input at 1.2 V	–20		20	μA
		V _I = 4 V, Other input at 1.2 V	0		33	
	Input current (A or B inputs 'LVDT)	V _I = 0 V or 2.4 V, Other input open	–40		40	μA
		V _I = 4 V, Other input open	0		66	
I _{I(OFF)}	Input current (A or B inputs 'LVDS)	V _{CC} = 1.5 V, V _I = 0 V or 2.4 V, Other input at 1.2 V	–20		20	μA
		V _{CC} = 1.5 V, V _I = 2.4 V or 4 V, Other input at 1.2 V	0		33	
	Input current (A or B inputs 'LVDT)	V _{CC} = 1.5 V, V _I = 0 V or 2.4 V, Other input open	–40		40	μA
		V _{CC} = 1.5 V, V _I = 2.4 V or 4 V, Other input open	0		66	
I _{IO}	Input offset current (I _{IA} – I _{IB}) 'LVDS	V _{IA} = V _{IB} , 0 ≤ V _{IA} ≤ 4 V	–6		6	μA
R _T	Termination resistance ('LVDT)	V _{ID} = 300 mV and 500 mV, V _{IC} = 0 V to 2.4 V	90	110	132	Ω
	Termination resistance ('LVDT with power-off)	V _{ID} = 300 mV and 500 mV, V _{CC} = 1.5 V, V _{IC} = 0 V to 2.4 V	90	110	132	
C _I	Differential input capacitance ('LVDT with power-off)	V _I = 0.4 sin (4E6πt) + 0.5 V		3		pF
		Powered down (V _{CC} = 1.5 V)		3		

(1) All typical values are at 25°C and with a 3.3-V supply.

(2) The algebraic convention in which the least positive (most negative) limit is designated as minimum is used in this data sheet.

OUTPUT ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{OD}	Differential output voltage magnitude	See Figure 2	247	310	454	mV
Δ V _{OD}	Change in differential output voltage magnitude between logic states		–50		50	
V _{OC(SS)}	Steady-state common-mode output voltage	See Figure 3	1.125		1.375	V
ΔV _{OC(SS)}	Change in steady-state common-mode output voltage between logic states		–50		50	mV
V _{OC(PP)}	Peak-to-peak common-mode output voltage			50	150	mV
I _{OS}	Short-circuit output current	V _{O(Y)} or V _{O(Z)} = 0 V	–24		24	mA
I _{OS(D)}	Differential short-circuit output current	V _{OD} = 0 V	–12		12	mA
I _{OZ}	High-impedance output current	V _{OD} = 600 mV	–1		1	μA
		V _O = 0 V or V _{CC}	–1		1	
C _O	Differential output capacitance	V _I = 0.4 sin (4E6πt) + 0.5 V		3		pF

(1) All typical values are at 25°C and with a 3.3-V supply.

TIMING CHARACTERISTICS

PARAMETER		TEST CONDITIONS	MIN	NOM	MAX	UNIT
t_{SET}	Input to select setup time		0			ns
t_{HOLD}	Input to select hold time		0.5			ns
t_{SWITCH}	Select to switch output		1	2	2.6	ns

SWITCHING CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	NOM ⁽¹⁾	MAX	UNIT
t_{PLH}	Propagation delay time, low-to-high-level output	See Figure 4	400	650	900	ps
t_{PHL}	Propagation delay time, high-to-low-level output		400	650	900	ps
t_r	Differential output signal rise time (20% - 80%)				280	ps
t_f	Differential output signal fall time (20% - 80%)				280	ps
$t_{sk(p)}$	Pulse skew ($ t_{PHL} - t_{PLH} $) ⁽²⁾			10	50	ps
$t_{sk(pp)}$	Part-to-part skew ⁽³⁾	$V_{ID} = 0.2$ V			100	ps
$t_{jit(per)}$	Period jitter, rms (1 standard deviation) ⁽⁴⁾	750 MHz clock input ⁽⁵⁾		1	2.2	ps
$t_{jit(cc)}$	Cycle-to-cycle jitter (peak) ⁽⁴⁾	750 MHz clock input ⁽⁶⁾		10	17	ps
$t_{jit(pp)}$	Peak-to-peak jitter ⁽⁴⁾	1.5 Gbps 2 ²³ -1 PRBS input ⁽⁷⁾		33	65	ps
$t_{jit(det)}$	Deterministic jitter, peak-to-peak ⁽⁴⁾	1.5 Gbps 2 ⁷ -1 PRBS input ⁽⁸⁾		17	50	ps
t_{PHZ}	Propagation delay time, high-level-to-high-impedance output	See Figure 5		6	8	ns
t_{PLZ}	Propagation delay time, low-level-to-high-impedance output	See Figure 5		6	8	ns
t_{PZH}	Propagation delay time, high-impedance-to-high-level output	See Figure 5		4	6	ns
t_{PZL}	Propagation delay time, high-impedance-to-low-level output	See Figure 5		4	6	ns
$t_{sk(o)}$	Output skew ⁽⁹⁾			15	40	ps

(1) All typical values are at 25°C and with a 3.3-V supply.

(2) $t_{sk(p)}$ is the magnitude of the time difference between the t_{PLH} and t_{PHL} of any output of a single device.

(3) $t_{sk(pp)}$ is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

(4) Jitter is specified by design and characterization. Stimulus jitter has been subtracted.

(5) Input voltage = $V_{ID} = 200$ mV, 50% duty cycle at 750 MHz, $t_r = t_f = 50$ ps (20% to 80%), measured over 1000 samples.

(6) Input voltage = $V_{ID} = 200$ mV, 50% duty cycle at 750 MHz, $t_r = t_f = 50$ ps (20% to 80%).

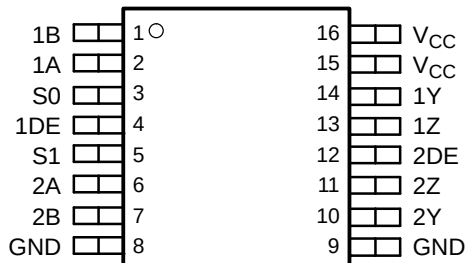
(7) Input voltage = $V_{ID} = 200$ mV, 2²³-1 PRBS pattern at 1.5 Gbps, $t_r = t_f = 50$ ps (20% to 80%), measured over 200 k samples.

(8) Input voltage = $V_{ID} = 200$ mV, 2⁷-1 PRBS pattern at 1.5 Gbps, $t_r = t_f = 50$ ps (20% to 80%).

(9) Output skew is the magnitude of the time delay difference between the outputs of a single device with all inputs tied together.

PIN ASSIGNMENT

D OR PW PACKAGE
(TOP VIEW)



Circuit Function Table

INPUTS ⁽¹⁾						OUTPUTS ⁽¹⁾		LOGIC DIAGRAM
1V _{ID}	2V _{ID}	S1	S0	1DE	2DE	1V _{OD}	2V _{OD}	
X	X	X	X	L	L	Z	Z	
> 100 mV	X	L	L	H	L	H	Z	
< -100 mV	X	L	L	H	L	L	Z	
< -100 mV	X	L	L	H	H	L	L	
> 100 mV	X	L	L	H	H	H	H	
> 100 mV	X	L	L	L	H	Z	H	
< -100 mV	X	L	L	L	H	Z	L	
> 100 mV	X	H	L	H	L	H	Z	
< -100 mV	X	H	L	H	L	L	Z	
< -100 mV	< -100 mV	H	L	H	H	L	L	
< -100 mV	> 100 mV	H	L	H	H	L	H	
> 100 mV	< -100 mV	H	L	H	H	H	L	
> 100 mV	> 100 mV	H	L	H	H	H	H	
X	> 100 mV	H	L	L	H	Z	H	
X	< -100 mV	H	L	L	H	Z	L	
X	> 100 mV	L	H	H	L	H	Z	
X	< -100 mV	L	H	H	L	L	Z	
X	< -100 mV	L	H	H	H	L	L	
X	> 100 mV	L	H	H	H	H	H	
X	> 100 mV	L	H	L	H	Z	H	
X	< -100 mV	L	H	L	H	Z	L	
X	> 100 mV	H	H	H	L	H	Z	
X	< -100 mV	H	H	H	L	L	Z	
< -100 mV	< -100 mV	H	H	H	H	L	L	
< -100 mV	> 100 mV	H	H	H	H	H	L	
> 100 mV	< -100 mV	H	H	H	H	L	H	
> 100 mV	> 100 mV	H	H	H	H	H	H	
> 100 mV	X	H	H	L	H	Z	H	
< -100 mV	X	H	H	L	H	Z	L	

(1) H = high level, L = low level, Z = high impedance, X = don't care

PARAMETER MEASUREMENT INFORMATION

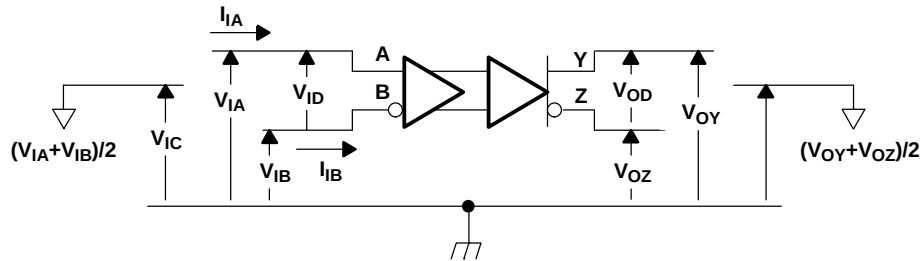


Figure 1. Voltage and Current Definitions

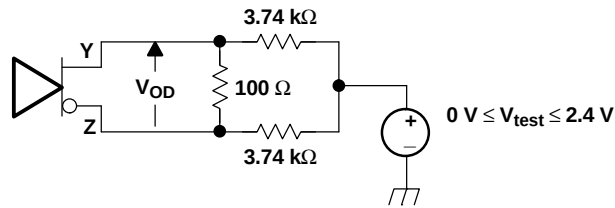
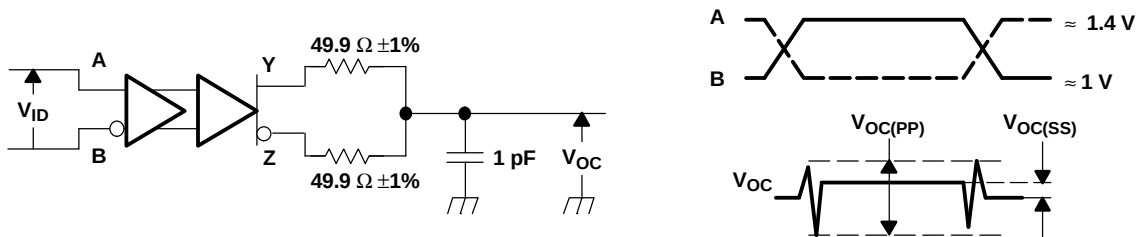
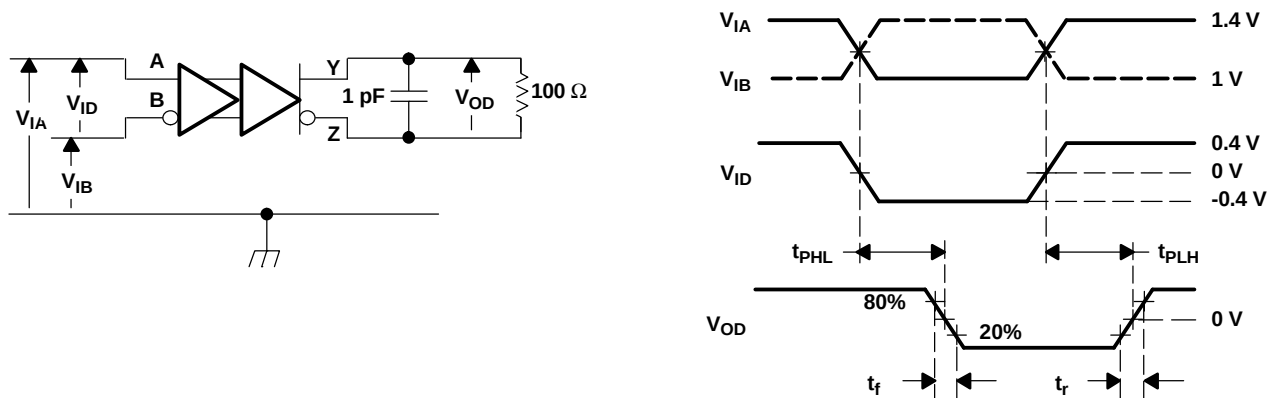


Figure 2. Differential Output Voltage (V_{OD}) Test Circuit



NOTE: All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 0.25$ ns, pulse repetition rate (PRR) = 0.5 Mpps, pulse width = 500 ± 10 ns; $R_L = 100 \Omega$; C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.; the measurement of $V_{OC(PP)}$ is made on test equipment with a -3-dB bandwidth of at least 300 MHz.

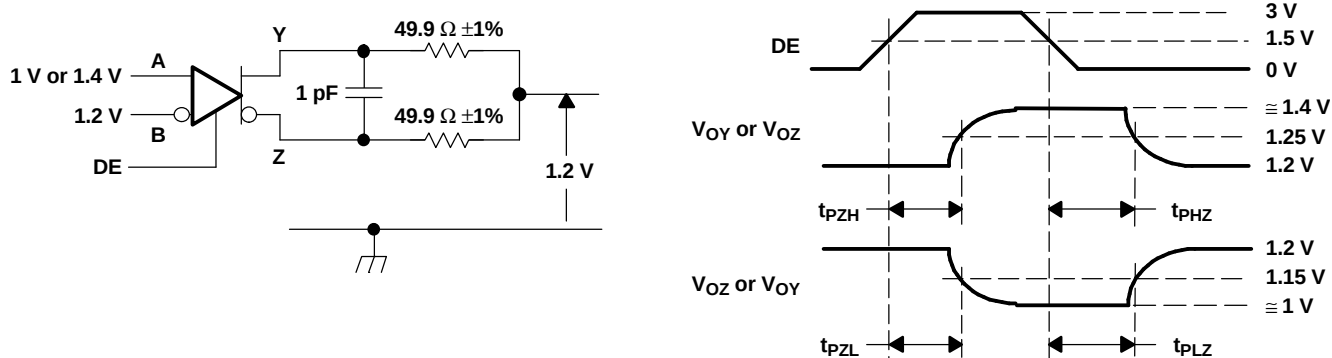
Figure 3. Test Circuit and Definitions for the Driver Common-Mode Output Voltage



NOTE: All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 0.25$ ns, pulse repetition rate (PRR) = 0.5 Mpps, pulse width = 500 ± 10 ns. C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.

Figure 4. Timing Test Circuit and Waveforms

PARAMETER MEASUREMENT INFORMATION (continued)



NOTE: All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1$ ns, pulse repetition rate (PRR) = 0.5 Mpps, pulse width = 500 ± 10 ns. C_L includes instrumentation and fixture capacitance within 0.06 mm of the D.U.T.

Figure 5. Enable and Disable Time Circuit and Definitions

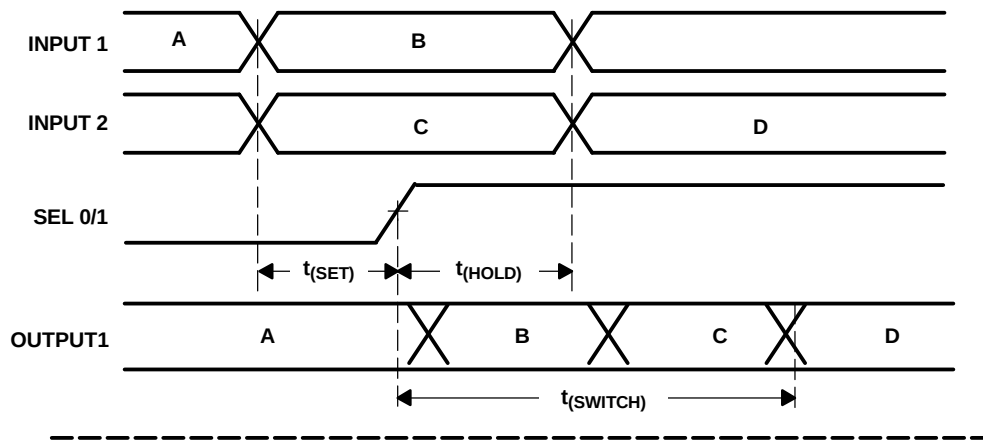


Figure 6. Example Switch, Setup, and Hold Times

PARAMETER MEASUREMENT INFORMATION (continued)

$t_{\text{(SET)}}$ and $t_{\text{(HOLD)}}$ times specify that data must be in a stable state before and after multiplex control switches.

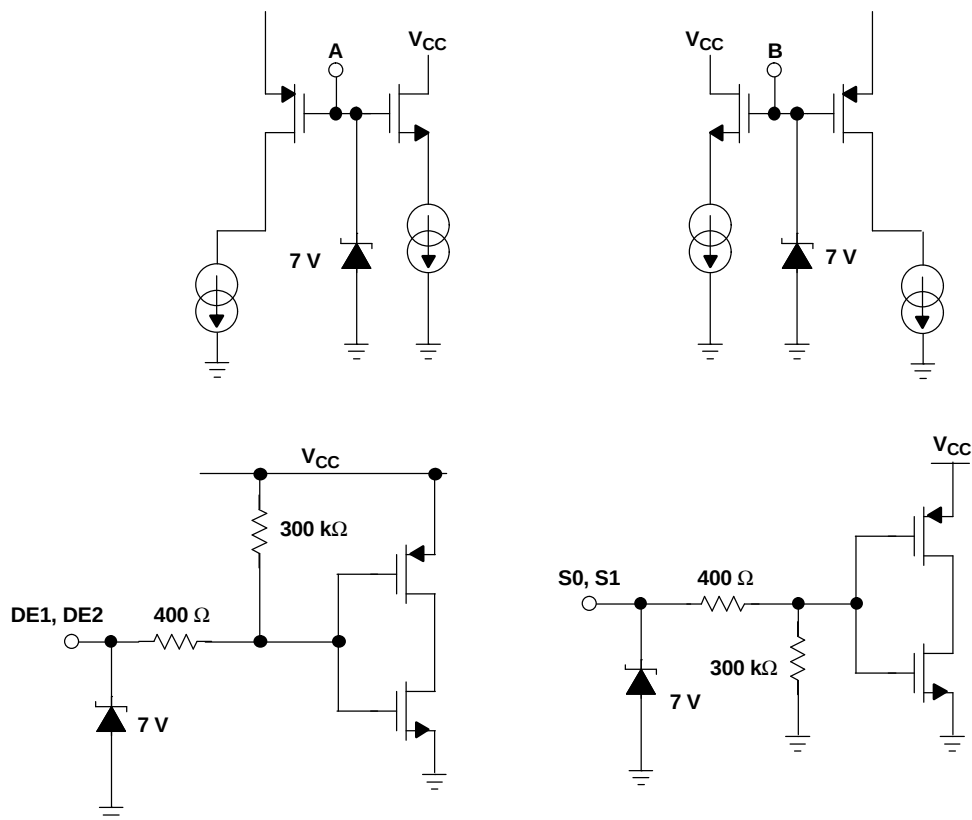
Table 1. Receiver Input Voltage Threshold Test

APPLIED VOLTAGES		RESULTING DIFFERENTIAL INPUT VOLTAGE	RESULTING COMMON-MODE INPUT VOLTAGE	OUTPUT ⁽¹⁾
V_{IA}	V_{IB}	V_{ID}	V_{IC}	
1.25 V	1.15 V	100 mV	1.2 V	H
1.15 V	1.25 V	–100 mV	1.2 V	L
4.0 V	3.9 V	100 mV	3.95 V	H
3.9 V	4.0 V	–100 mV	3.95 V	L
0.1 V	0.0 V	100 mV	0.05 V	H
0.0 V	0.1 V	–100 mV	0.05 V	L
1.7 V	0.7 V	1000 mV	1.2 V	H
0.7 V	1.7 V	–1000 mV	1.2 V	L
4.0 V	3.0 V	1000 mV	3.5 V	H
3.0 V	4.0 V	–1000 mV	3.5 V	L
1.0 V	0.0 V	1000 mV	0.5 V	H
0.0 V	1.0 V	–1000 mV	0.5 V	L

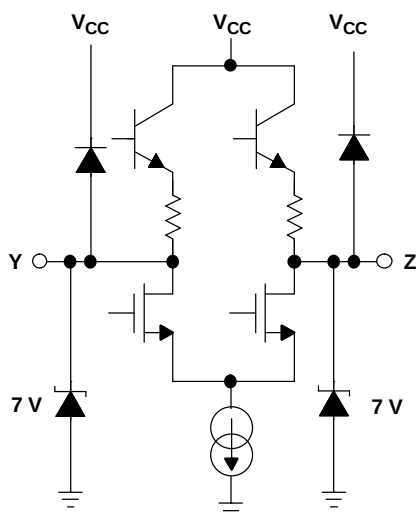
(1) H = high level, L = low level

EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS

INPUT LVDS122



OUTPUT LVDS122



TYPICAL CHARACTERISTICS

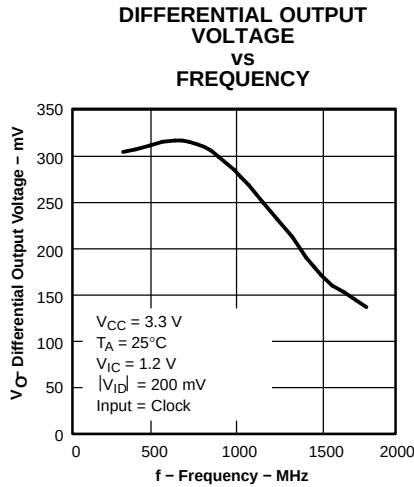


Figure 7.

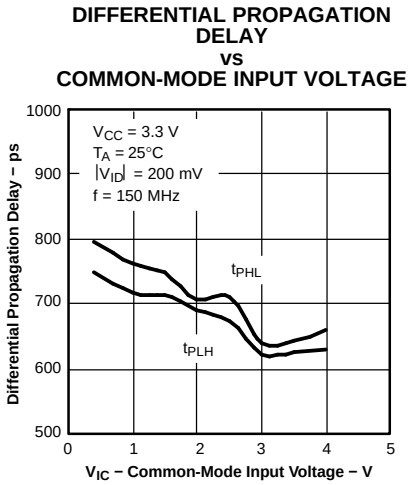


Figure 8.

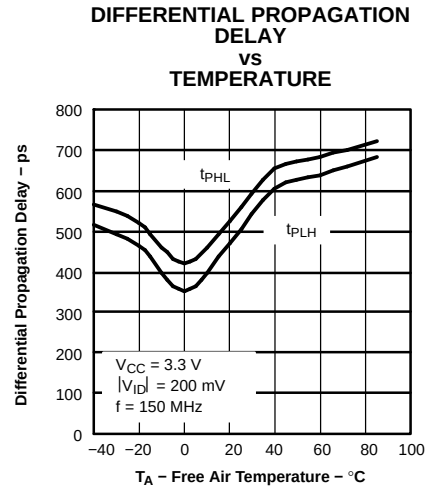


Figure 9.

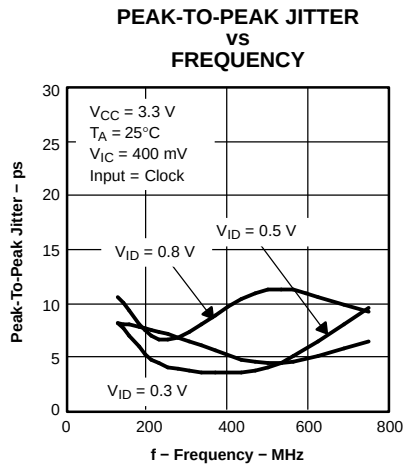


Figure 10.

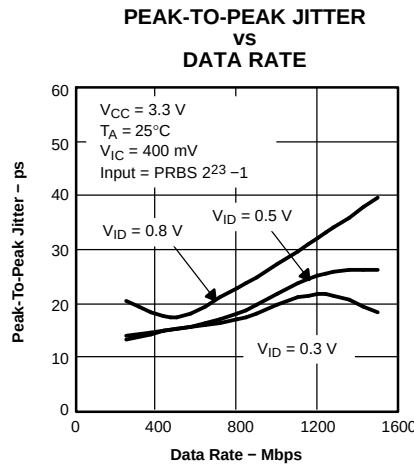


Figure 11.

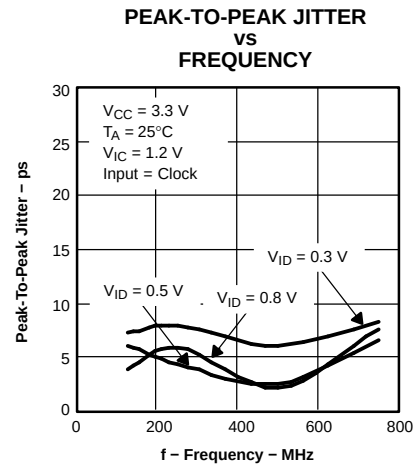


Figure 12.

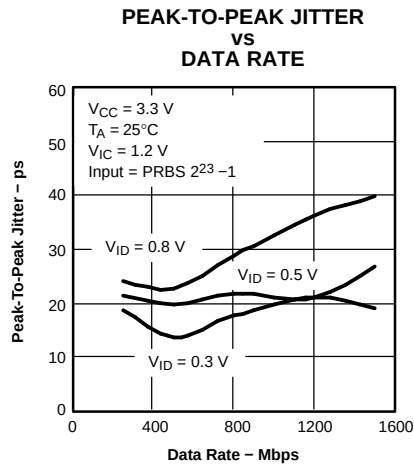


Figure 13.

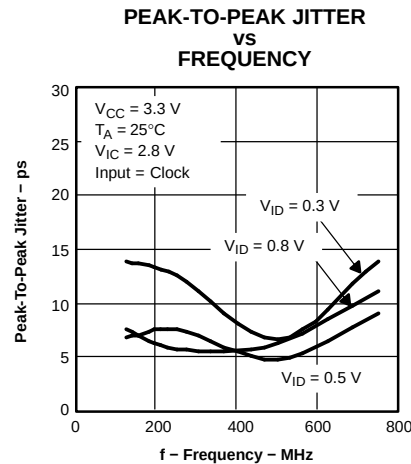


Figure 14.

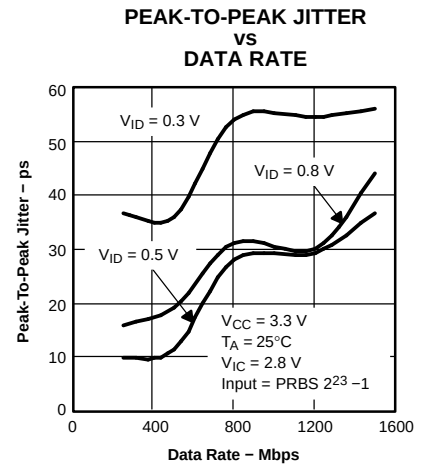


Figure 15.

TYPICAL CHARACTERISTICS (continued)

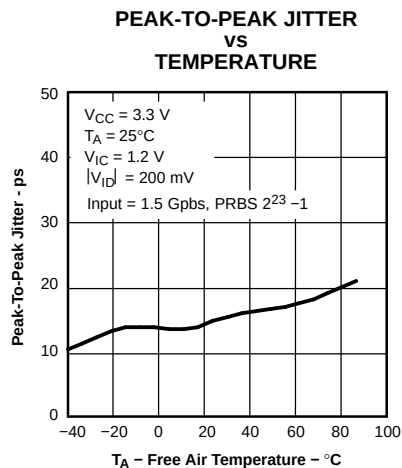


Figure 16.

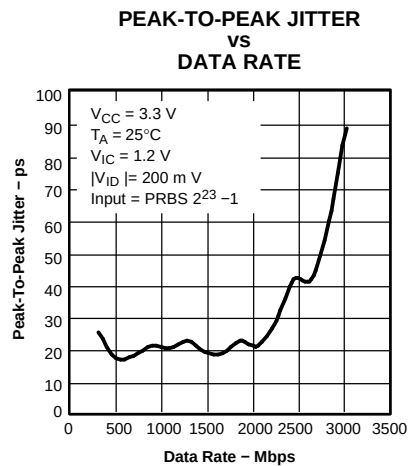
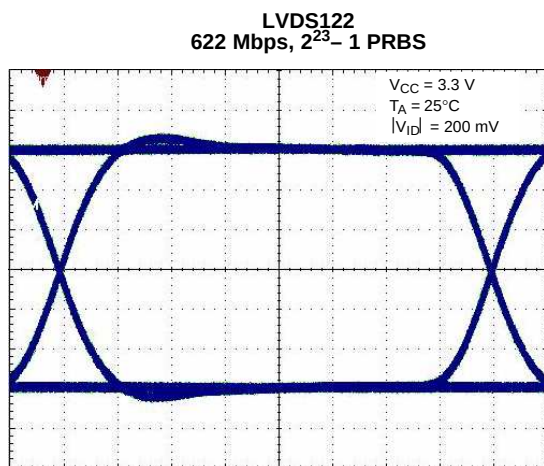
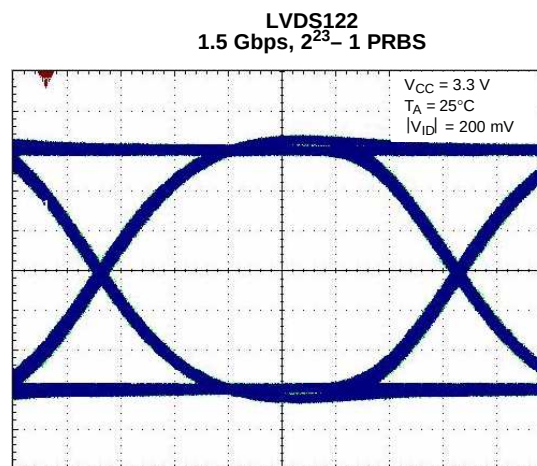


Figure 17.



Horizontal Scale= 200 ps/div
LVPECL-to-LVDS

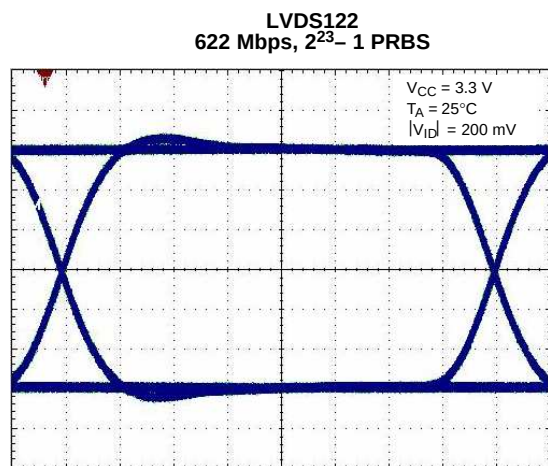
Figure 18.



Horizontal Scale= 100 ps/div
LVPECL-to-LVDS

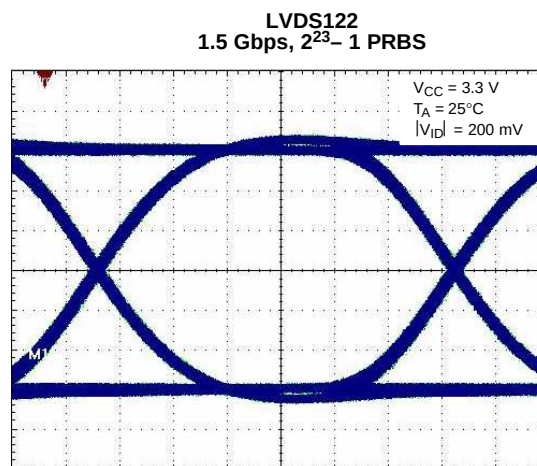
Figure 19.

TYPICAL CHARACTERISTICS (continued)



Horizontal Scale= 200 ps/div
LVDS-to-LVDS

Figure 20.



Horizontal Scale= 100 ps/div
LVDS-to-LVDS

Figure 21.

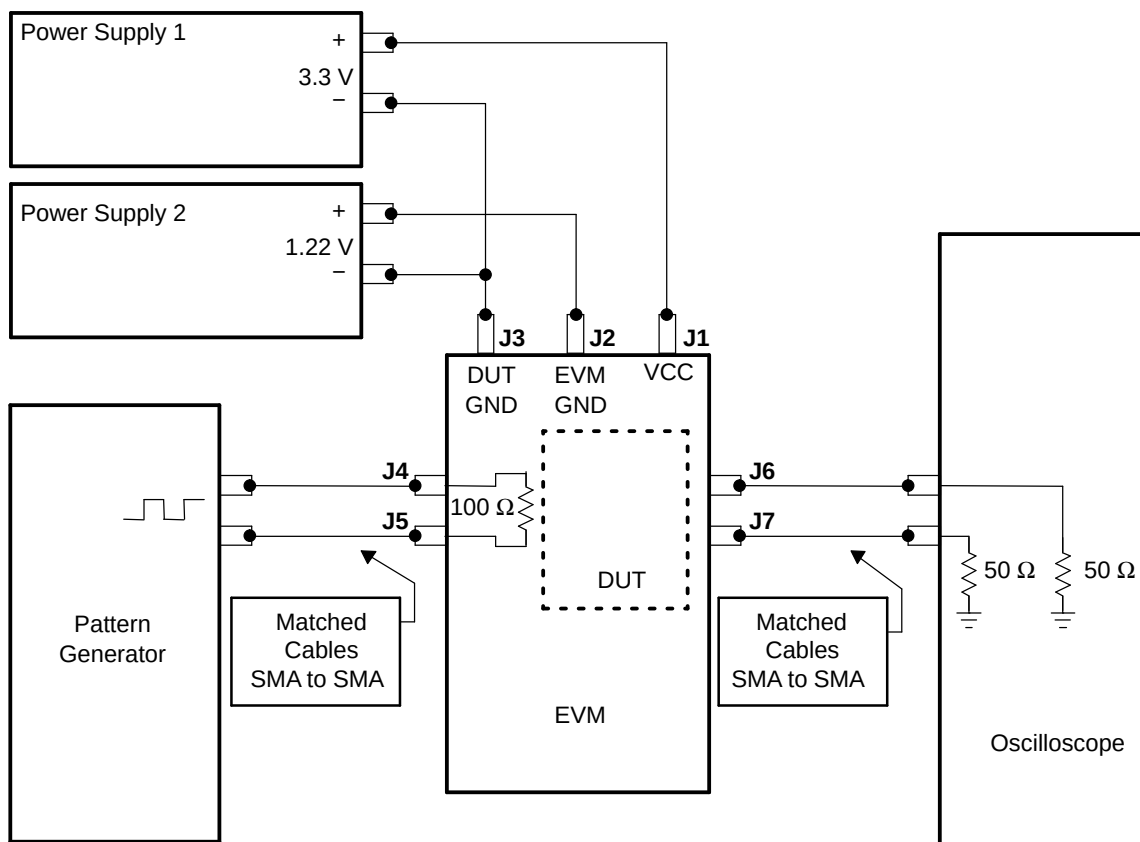


Figure 22. Jitter Setup Connections for SN65LVDS122

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN65LVDS122D	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDS122
SN65LVDS122D.B	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDS122
SN65LVDS122DR	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDS122
SN65LVDS122DR.B	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDS122
SN65LVDS122PW	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDS122
SN65LVDS122PW.B	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDS122
SN65LVDS122PWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDS122
SN65LVDS122PWR.B	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDS122
SN65LVDS122PWRG4	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDS122
SN65LVDS122PWRG4.B	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDS122
SN65LVDT122D	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDT122
SN65LVDT122D.B	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDT122
SN65LVDT122PW	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDT122
SN65LVDT122PW.B	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDT122
SN65LVDT122PW1G4	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDT122
SN65LVDT122PW1G4.B	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDT122
SN65LVDT122PWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDT122
SN65LVDT122PWR.B	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVDT122

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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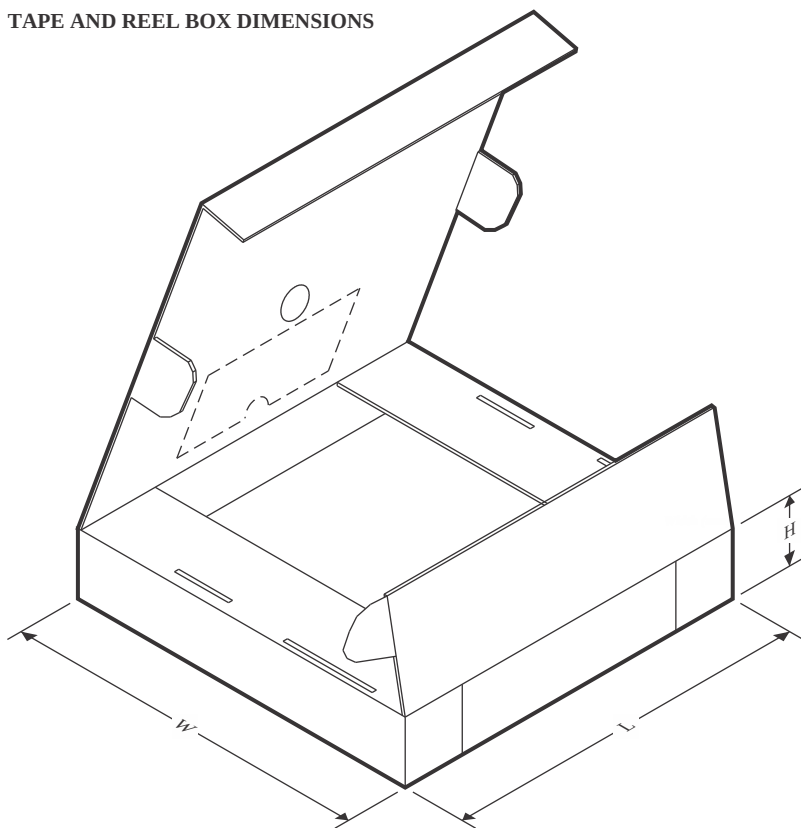
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LVDS122DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN65LVDS122PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN65LVDS122PWRG4	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN65LVDT122PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LVDS122DR	SOIC	D	16	2500	350.0	350.0	43.0
SN65LVDS122PWR	TSSOP	PW	16	2000	350.0	350.0	43.0
SN65LVDS122PWRG4	TSSOP	PW	16	2000	350.0	350.0	43.0
SN65LVDT122PWR	TSSOP	PW	16	2000	350.0	350.0	43.0

TUBE

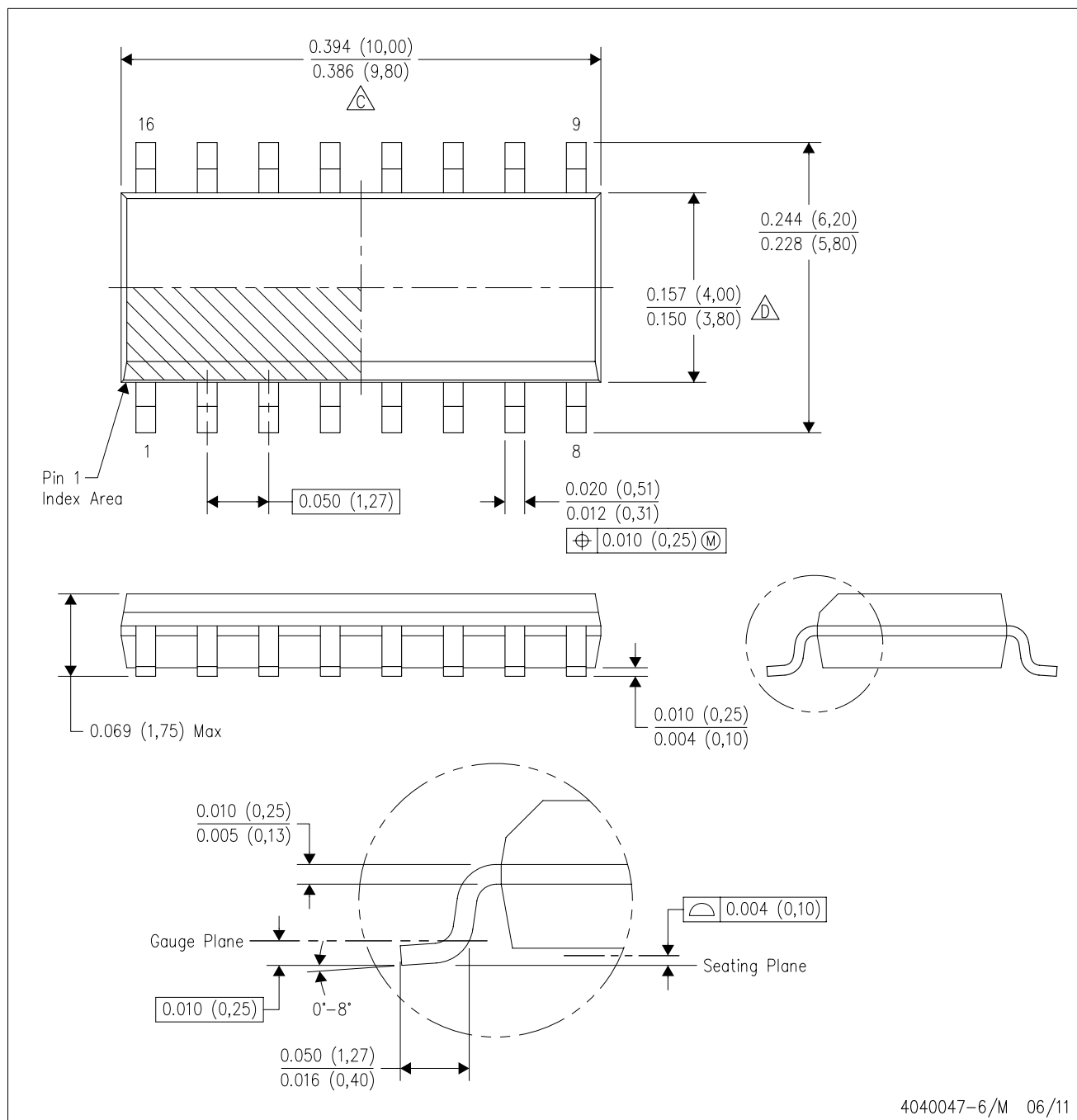


*All dimensions are nominal

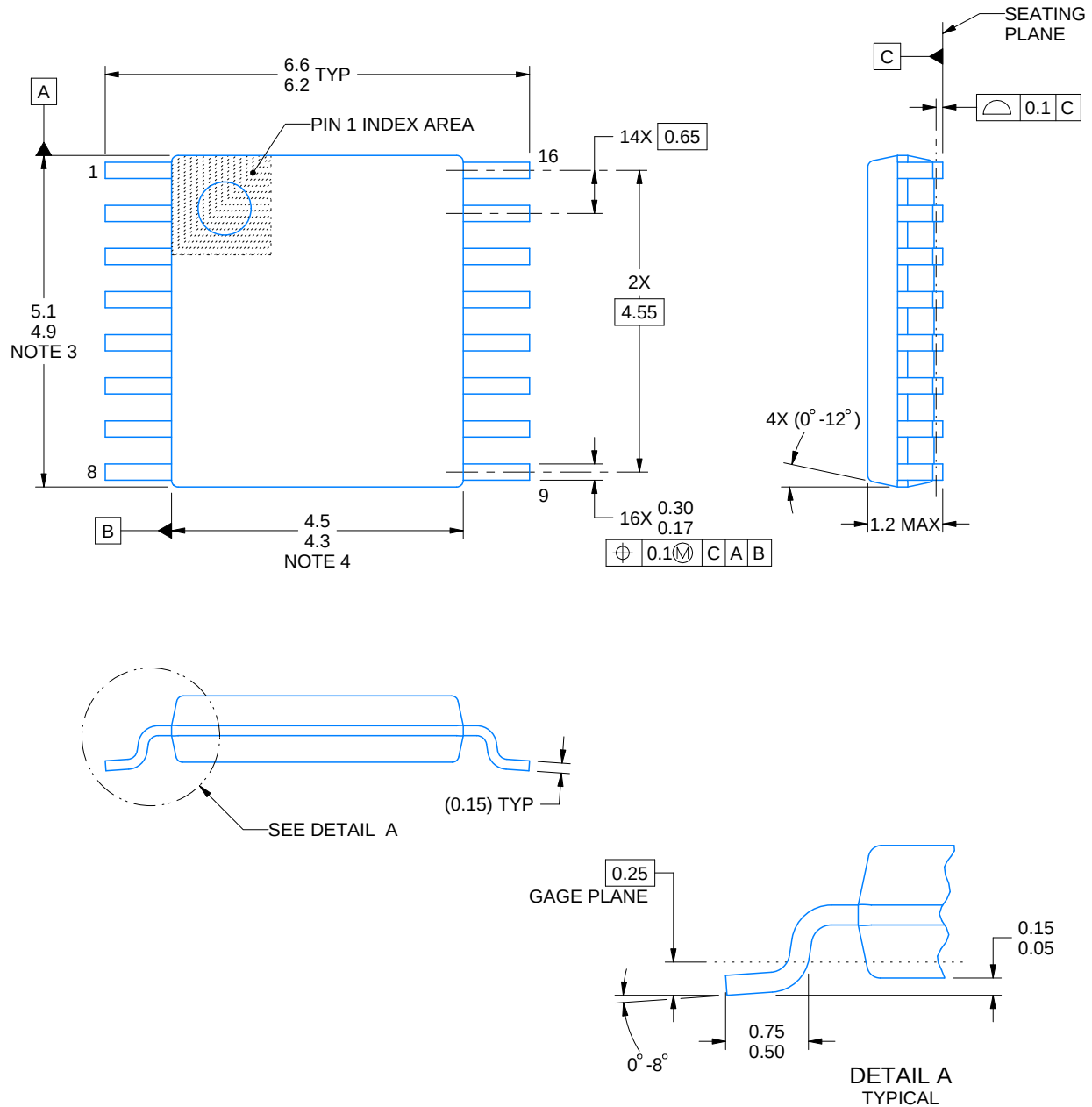
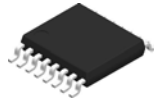
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN65LVDS122D	D	SOIC	16	40	505.46	6.76	3810	4
SN65LVDS122D.B	D	SOIC	16	40	505.46	6.76	3810	4
SN65LVDS122PW	PW	TSSOP	16	90	530	10.2	3600	3.5
SN65LVDS122PW.B	PW	TSSOP	16	90	530	10.2	3600	3.5
SN65LVDT122D	D	SOIC	16	40	505.46	6.76	3810	4
SN65LVDT122D.B	D	SOIC	16	40	505.46	6.76	3810	4
SN65LVDT122PW	PW	TSSOP	16	90	530	10.2	3600	3.5
SN65LVDT122PW.B	PW	TSSOP	16	90	530	10.2	3600	3.5
SN65LVDT122PW1G4	PW	TSSOP	16	90	530	10.2	3600	3.5
SN65LVDT122PW1G4.B	PW	TSSOP	16	90	530	10.2	3600	3.5

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AC.



4220204/B 12/2023

NOTES:

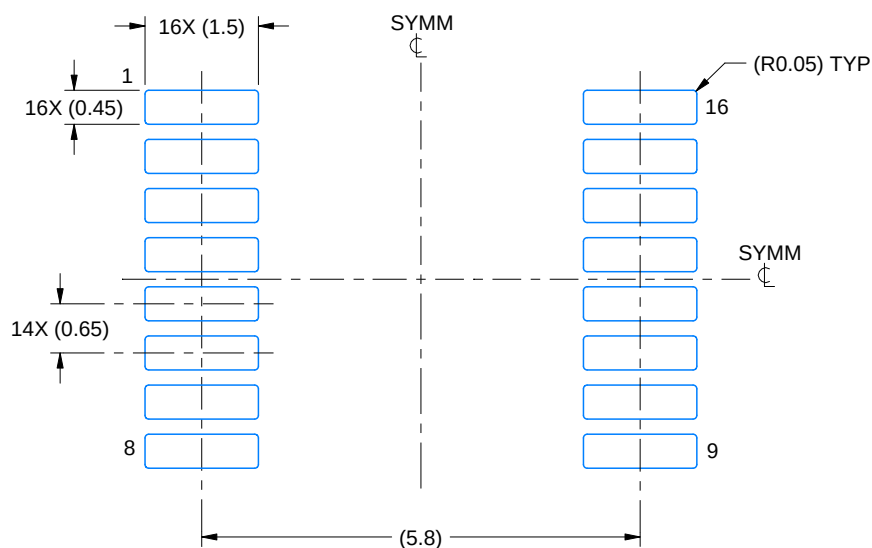
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

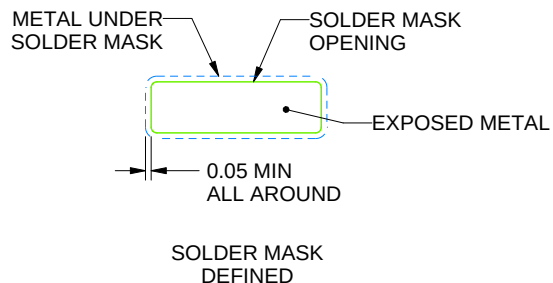
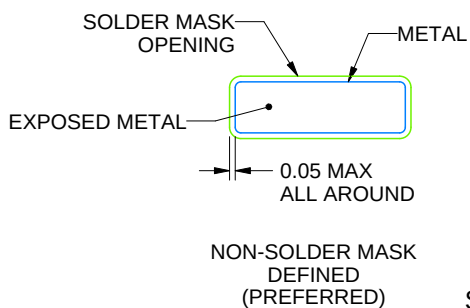
PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220204/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

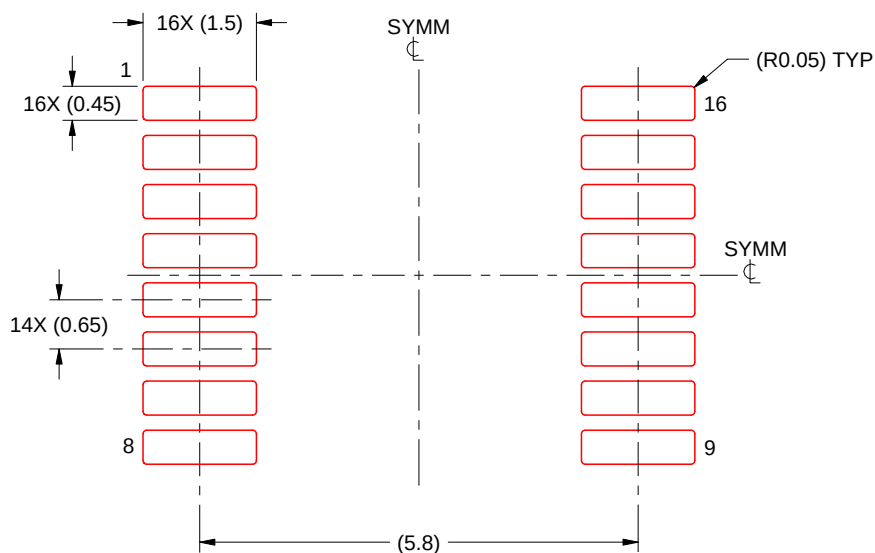
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



4220204/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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